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## NTE3035A Phototransistor Detector

### Description:

The NTE3035A is designed for a wide variety of industrial processing and control applications requiring a sensitive detector. The NTE3034A is an identical package and is designed to be used with the NTE3029A infrared emitter.

### Features:

- Miniature, Low Profile, Clear Plastic Package
- Designed for Automatic Handling and Accurate Positioning
- Side Looking, with Molded Lens
- High Volume, Economical

**Absolute Maximum Ratings:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Collector-Emitter Voltage, $V_{CEO}$ .....	60V
Total Device Dissipation ( $T_A = +25^\circ\text{C}$ ), $P_D$ .....	150mW
Derate Above $25^\circ\text{C}$ (Note 1) .....	$2\text{mW}/^\circ\text{C}$
Operating Junction Temperature Range, $T_J$ .....	$-40^\circ$ to $+100^\circ\text{C}$
Storage Temperature Range, $T_{stg}$ .....	$-40^\circ$ to $+100^\circ\text{C}$
Lead Temperature (During Soldering, 1/16" from case, 5sec max., Note 2), $T_L$ .....	$+260^\circ\text{C}$

**Electrical Characteristics:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Dark Current	$I_D$	$V_{CE} = 10\text{V}$ , $H \approx 0$	—	—	100	nA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 10\text{mA}$ , $H \approx 0$	60	—	—	V
Capacitance	$C_{ce}$	$V_{CC} = 5\text{V}$ , $f = 1\text{MHz}$	—	3.9	—	pF

**Optical Characteristics:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Light Current	$I_L$	$V_{CE} = 5\text{V}$ , $H = 500\mu\text{W}/\text{cm}^2$ , $\lambda = 940\text{nm}$	5	25	—	mA
Turn-On Time	$t_{on}$	$H = 500\mu\text{W}/\text{cm}^2$ , $V_{CC} = 5\text{V}$ , $R_L = 100\Omega$	—	125	—	$\mu\text{s}$
Turn-Off Time	$t_{off}$		—	150	—	$\mu\text{s}$
Saturation Voltage	$V_{CE(\text{sat})}$	$H = 500\mu\text{W}/\text{cm}^2$ , $\lambda = 940\text{nm}$ , $I_C = 2\text{mA}$ , $V_{CC} = 5\text{V}$	—	0.75	1.0	V
Wavelength of Maximum Sensitivity	$\lambda_s$		—	0.8	—	$\mu\text{m}$

Note 1. Measured with device soldered into a typical PC board.

Note 2. Heat sink should be applied to leads during soldering to prevent case temperature from exceeding  $+100^\circ\text{C}$ .

